

## SCHOTTKY BARRIER RECTIFIERS

VOLTAGE RANGE: 20 --- 100 V  
CURRENT: 1.0A

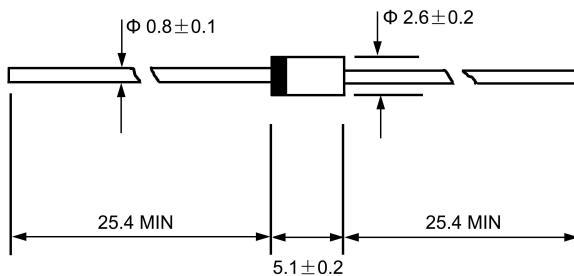
## FEATURES

- ◇ Metal-Semiconductor junction with guard ring
- ◇ Epitaxial construction
- ◇ Low forward voltage drop, low switching losses
- ◇ High surge capability
- ◇ For use in low voltage, high frequency inverters free wheeling, and polarity protection applications
- ◇ The plastic material carries U/L recognition 94V-0

## MECHANICAL DATA

- ◇ Case: JEDEC DO-41, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.012 ounces, 0.34 grams
- ◇ Mounting position: Any

DO - 41



Dimensions in millimeters

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		SR120	SR130	SR140	SR150	SR160	SR180	SR1A0	UNITS				
Maximum recurrent peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	80	100	V				
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	56	70	V				
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	V				
Maximum average forward rectified current 9.5mm lead length, (see fig.1)	I <sub>F(AV)</sub>	1.0						A					
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @T <sub>j</sub> =125°C	I <sub>FSM</sub>	40.0						A					
Maximum instantaneous forward voltage @ 1.0A (Note 1)	V <sub>F</sub>	0.55		0.7		0.85		V					
Maximum reverse current @T <sub>A</sub> =25°C at rated DC blocking voltage @T <sub>A</sub> =100°C	I <sub>R</sub>	0.5 10.0						mA					
Typical junction capacitance (Note 2)	C <sub>J</sub>	110						pF					
Typical thermal resistance (Note 3)	R <sub>θJA</sub>	50						°C/W					
Operating junction temperature range	T <sub>J</sub>	- 55 ---- + 125		- 55 ---- + 150				°C					
Storage temperature range	T <sub>STG</sub>	- 55 ---- +150						°C					

NOTE: 1. Pulse test : 300 μs pulse width, 1% duty cycle.

www.galaxychn.com

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to ambient

# RATINGS AND CHARACTERISTIC CURVES

**SR120 --- SR1A0**

FIG.1 -- FORWARD DERATING CURVE

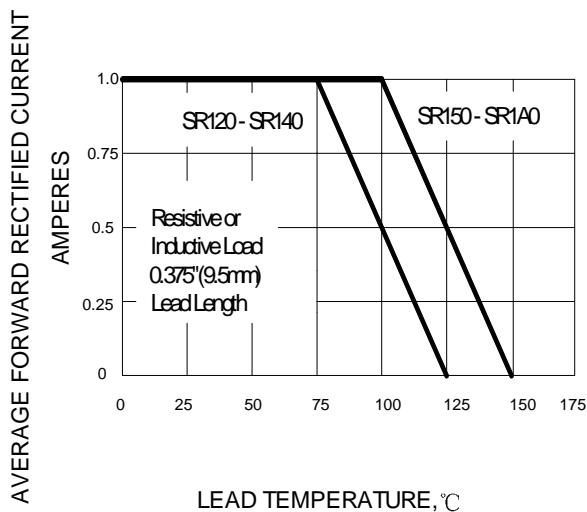


FIG.2 -- PEAK FORWARD SURGE CURRENT

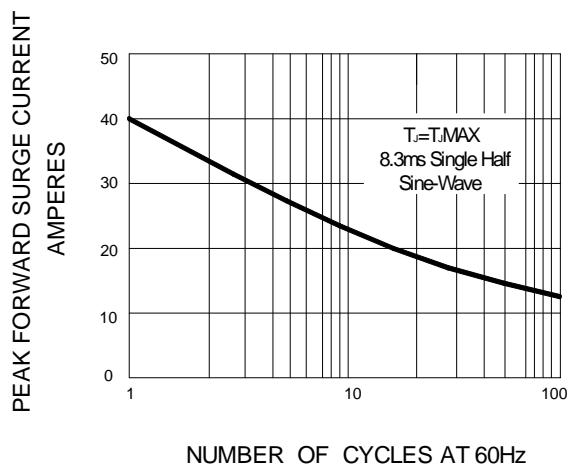


FIG.3 -- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

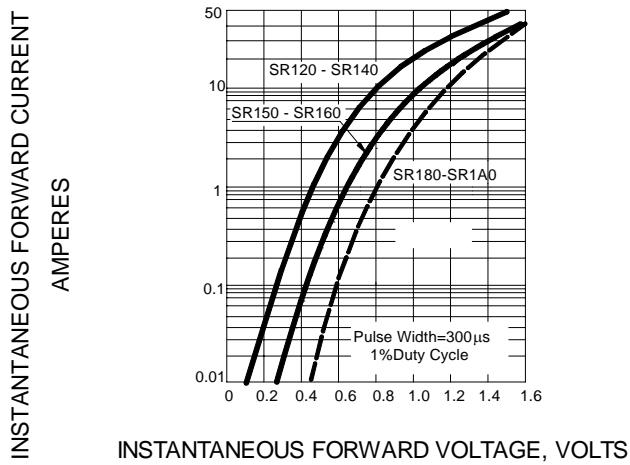


FIG.4 -- TYPICAL JUNCTION CAPACITANCE

